

TN5335N8-G Information



For Reference Only

Part Number TN5335N8-G

Manufacturer Microchip Technology

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 350V 0.23A SOT89-3

Package TO-243AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









TN5335N8-G Specifications

Manufacturer Part Number	TN5335N8-G
Manufacturer	Microchip Technology
Category	Discrete Semiconductor Products
Category	
Deslares	Transistors - FETs, MOSFETs - Single
Package	TO-243AA
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	350V
Current - Continuous Drain (Id) @ 25°C	230mA (Tj)
Drive Voltage (Max Rds On, Min Rds On)	3V, 10V
Vgs(th) (Max) @ Id	2V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	110pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	1.6W (Ta)
Rds On (Max) @ Id, Vgs	15 Ohm @ 200mA, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	TO-243AA (SOT-89)
Package / Case	TO-243AA
	Report errors?

TN5335N8-G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

TN5335N8-G Payment Methods



















TN5335N8-G Shipping Methods













If you have any question about TN5335N8-G, please do not hesitate to contact us!

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